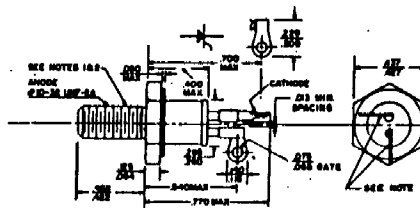


2N1773

SILICON CONTROLLED RECTIFIER



NOTE 1: COMPLETE THREADS EXTEND TO WITHIN 2-1/2 THREADS OF HEAD  
 2: DIAMETER OF UNTHREADED PORTION IS .047  
 3: ANGULAR ORIENTATION OF THESE TERMINALS IS UNDEFINED  
 4: CASE IS ANODE CONNECTION  
 5: ALL DIMENSIONS IN INCHES

Type	Minimum Forward Breakover Voltage ( $V_{BO}$ )† $T_J = -65^\circ\text{C to } +125^\circ\text{C}$	Repetitive Peak Reverse Voltage (PRV)† $T_J = -65^\circ\text{C to } +125^\circ\text{C}$	Transient Peak Reverse Voltage (Non-recurrent < 5 Millisec.) $T_J = -65^\circ\text{C to } +125^\circ\text{C}$
2N1773	150 Volts*	150 Volts*	225 Volts*

†Values apply for zero or negative gate voltage only. Maximum case to ambient thermal resistance for which maximum PRV ratings apply equals  $18^\circ\text{C/watt}$ .

Test	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Peak Reverse and Forward Blocking Current†	$i_{R}$ and $i_{F}$	—	4.0	8.0	ma	$T_J = 125^\circ\text{C}$ , Gate Open 150
Full Cycle Avg. Reverse and Forward Blocking Current†	$I_{R(AV)}$ and $I_{F(AV)}$	—	2.0	4.0*	mAdc	$T_J = 60^\circ\text{C}$ , $I_L = 4.7\text{A}$ , half sine wave 180° Conduction Angle 150
Gate Current to Fire	$I_{GF}$	—	10	15	mAdc	$V_{AR} = 12\text{Vdc}$ , $T_J = 25^\circ\text{C}$ , $R_L = 250\text{ ohms}$
		—	20	30*	mAdc	$V_{AR} = 12\text{Vdc}$ , $T_J = -65^\circ\text{C}$ , $R_L = 250\text{ ohms}$
		—	4	8	mAdc	$V_{AR} = 12\text{Vdc}$ , $T_J = 125^\circ\text{C}$ , $R_L = 250\text{ ohms}$
Gate Voltage to Fire	$V_{GF}$	—	1.3	2.0*	Vdc	$V_{AR} = 12\text{Vdc}$ , $T_J = -65^\circ\text{ to } +125^\circ\text{C}$ , $R_L = 250\text{ ohms}$
		0.3*	0.7	—	Vdc	$V_{AR} = \text{Rated}$ , $T_J = 125^\circ\text{C}$ , $R_L = 250\text{ ohms}$
Peak Forward Voltage Drop	$V_F$	—	1.6	1.85	v	$T_J = 25^\circ\text{C}$ , $i_F = 15\text{ a}$ (single sinusoidal pulse, 4 ms wide)
Holding Current	$I_H$	—	8.0	—	mAdc	Anode Supply = 6 Vdc, $T_J = 25^\circ\text{C}$
Turn-on Time	$t_{on} + t_r$	—	1.0	—	$\mu\text{sec}$	$T_J = 25^\circ\text{C}$ , $i_F = 10\text{ a}$ , $V_{AR} = \text{Rated}$ Gate Supply: 7 volt open circuit, 20 ohm, 0.1 $\mu\text{sec}$ max. rise time.
Turn-off Time	$t_{off}$	—	15	—	$\mu\text{sec}$	$T_J = 125^\circ\text{C}$ , $i_F = 5\text{ a}$ , $i_R = 5\text{ a}$ $V_{AR}$ (Reapplied) = Rated. Rate of Rise of Reapplied Forward Blocking Voltage = 20 volts per microsecond maximum.
Thermal Resistance	$\theta_{J-C}$	—	1.5	3.1	$^\circ\text{C/Watt}$	Junction to Case.

†Values apply for zero or negative gate voltage. Maximum case to ambient thermal resistance for which maximum PRV ratings apply =  $18^\circ\text{C per watt}$ .

\*Indicates data included on JEDEC type number registration.

